

# (CURRENT ELECTRICITY)

①

(CHAPTER-3)

## ELECTRIC CURRENT (I)

It is defined as rate of flow of electric charge through any cross section of a conductor.

$$I = \frac{\text{total charge}}{\text{time taken}}$$
$$I = \frac{q}{t} = \frac{ne}{t}$$
$$I = \lim_{\Delta t \rightarrow 0} \frac{\Delta q}{\Delta t} = \frac{dq}{dt}$$

→ Scalar quantity

SI unit → A

CGS unit → st A

## CURRENT DENSITY (J):-

It is the ratio of the current at that point in the conductor to the area of the cross section of the conductor at that point.

$$J = \frac{I}{A}$$

$$I = JA$$

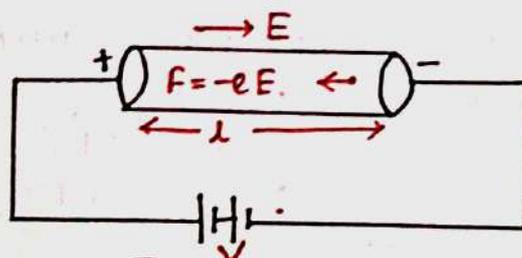
$$\rightarrow \boxed{I = \vec{J} \cdot \vec{A}}$$

→ Vector quantity.

## DRIFT VELOCITY ( $v_d$ )

It is defined as avg. velocity gained by the free  $e^-$ s of a conductor in the opposite direction of the externally applied electric field.

## DRIFT OF ELECTRONS:-



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If  $\vec{v}_1, \vec{v}_2, \dots, \vec{v}_N$  be the velocities of N no of free electrons,

Then, avg velocities of electrons =  $\frac{\vec{v}_1 + \vec{v}_2 + \dots + \vec{v}_N}{N} = 0$

Thus, there is no net flow of charge in any direction. In the presence of electric field, each  $e^-$  experiences a force,  $\vec{F} = -e\vec{E}$

The negative sign indicate  $e^-$  are moving in the opp. direction of  $\vec{E}$ .

$$\begin{aligned} \vec{F} &= -e\vec{E} \\ \Rightarrow m\vec{a} &= -e\vec{E} \\ \Rightarrow \vec{a} &= \frac{-e\vec{E}}{m}, \quad m = \text{mass of the electron.} \end{aligned}$$

If n, no. of  $e^-$  gain velocity component

$$\vec{v}_1, \vec{v}_2, \dots, \vec{v}_n$$

$$\vec{v}_1 = \vec{v}_1 + \vec{a}t_1$$

$$\vec{v}_2 = \vec{v}_2 + \vec{a}t_2$$

$$\vdots$$

$$\vec{v}_n = \vec{v}_n + \vec{a}t_n$$

$$\vec{v}_1 + \vec{v}_2 + \dots + \vec{v}_n = \vec{v}_1 + \vec{v}_2 + \dots + \vec{v}_n + \vec{a}(t_1 + t_2 + \dots + t_n)$$

$$\Rightarrow \frac{\vec{v}_1 + \vec{v}_2 + \dots + \vec{v}_n}{n} = \frac{\vec{v}_1 + \vec{v}_2 + \dots + \vec{v}_n}{n} + \frac{\vec{a}(t_1 + t_2 + \dots + t_n)}{n}$$

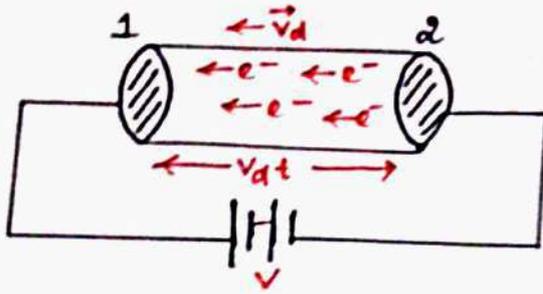
$$\Rightarrow \vec{v}_d = \vec{a}\tau, \quad \begin{aligned} v_d &= \text{drift velocity} \\ \tau &= \text{relaxation time.} \end{aligned}$$

$\tau$  is the avg. time elapsed between 2 successive collision of the electron.

$$\vec{v}_d = \frac{-e\vec{E}\tau}{m}$$

## RELATION BETWEEN ELECTRIC CURRENT AND DRIFT VELOCITY :-

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$A$  = area of the cross-section  
 $n$  = full electron density  
 $t$  = time taken by electron to move from cross-section 1 to 2.

distance bet<sup>n</sup> two cross-section =  $v_d t$

Volume bounded by two cross-section =  $Al = Av_d t$

no. of electrons in that volume =  $nAv_d t$

no. of electron passes through the cross-section 1 in time  $t = nAv_d t$

$$I = \frac{q}{t} = \frac{nAv_d t \cdot e}{t} = neAv_d$$

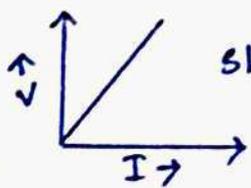
$$I = neAv_d$$

## OHM'S LAW :-

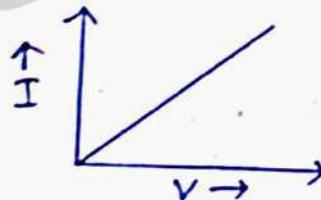
The potential difference between two ends of a conductor is directly proportional to current passing through it at constant temperature.

$$V \propto I$$

$$\Rightarrow V = IR$$



$$\text{slope} = \frac{V}{I} = R$$



$$\text{slope} = \frac{I}{V} = \frac{1}{R}$$

## DEDUCTION OF OHM'S LAW :-

$$I = neAv_d$$

$$= neA \left( \frac{eVt}{ml} \right) = \left( \frac{ne^2 A t}{ml} \right) V$$

$$V = \left( \frac{ml}{ne^2 A t} \right) I$$

$$\Rightarrow V = RI$$

$$\Rightarrow V \propto I$$

$$R = \frac{ml}{ne^2 A t}$$

constant for a particular conductor at constant temp.

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### LIMITATIONS OF OHM'S LAW:-

- ① only valid at constant temp.
- ② some substances do not obey ohm's law.

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### VECTOR FORM OF OHM'S LAW:-

$$\begin{aligned} J &= \frac{I}{A} \\ &= \frac{neAv_d}{A} \\ &= n \cdot \frac{eE\tau}{m} \cdot e \\ &= \left( \frac{ne^2\tau}{m} \right) E \end{aligned}$$

$$J = \sigma E$$

In vector form.

$$\vec{J} = \sigma \vec{E}$$

RESISTANCE (R):- It is defined as the opposition offered to the flow of current

SI unit  $\rightarrow \Omega$

CGS unit  $\rightarrow \text{st } \Omega / \text{ab } \Omega$

$$R = \frac{ml}{nAe^2\tau}$$

Resistance depends on:-

- ① Geometry of conductor
- ② Nature of material
- ③ Temperature.

CONDUCTANCE (G):- It is defined as the reciprocal of resistance.

$$G = \frac{1}{R} = \frac{nAe^2\tau}{mL}$$

SI unit. -  $\Omega^{-1}$

RESISTIVITY ( $\rho$ ):

$$R = \frac{m l}{n A e^2 \tau}$$

$$= \left( \frac{m}{n e^2 \tau} \right) \frac{l}{A}$$

$$\Rightarrow R = \rho \frac{l}{A} \quad \text{where } \rho = \frac{m}{n e^2 \tau}, \text{ which is constant for a particular material at constant temp.}$$

DEFINITION OF  $\rho$ :-  $\rho = \frac{R A}{L}$ ,  $A = 1 \text{ m}^2$ ,  $L = 1 \text{ m}$ ,  $\rho = R$

It is defined as resistance of a rod of that material of length 1m and area of cross section  $1 \text{ m}^2$ .

SI unit  $\rightarrow \Omega \text{ m}$

$$R = \frac{\rho L}{A}, \quad R \propto L \quad (A \text{ is constant})$$

$$R \propto \frac{1}{A} \quad (L \text{ is constant})$$

SPECIAL CASE:-CASE-I

When  $A$  is not constant

$$R = \rho \frac{l}{A} \times \frac{l}{l}$$

$$= \frac{\rho l^2}{\text{Vol}}$$

$$\Rightarrow R \propto l^2$$

CASE-II

when  $l$  is not constant

$$R = \rho \frac{l}{A} \times \frac{A}{A} = \frac{\rho l A}{A^2}$$

$$= \frac{\rho \times \text{Vol}}{A^2}$$

$$\Rightarrow R \propto \frac{l}{A^2}$$

CONDUCTIVITY ( $\sigma$ ):

It is defined as reciprocal of resistivity

$$\sigma = \frac{1}{\rho} = \frac{n e^2 \tau}{m}$$

SI unit:-  $\Omega^{-1} \text{ m}^{-1}$

### MOBILITY (μ)

Mobility of a charge is defined as drift velocity per unit electric field.

$$\mu = \frac{v_d}{E}$$

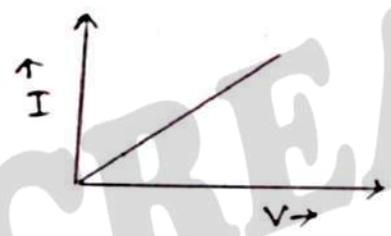
$$\mu = \frac{eE\tau}{m} \times \frac{1}{E}$$

$$\mu = \frac{e\tau}{m} \text{ (for electron)}$$

$$\mu = \frac{q\tau}{m} \text{ (general)}$$

- For a particular charge,  $\mu \propto \tau \propto \frac{1}{\text{temp}}$ .
- At constant temperature,  $\mu \propto \frac{q}{m}$ .

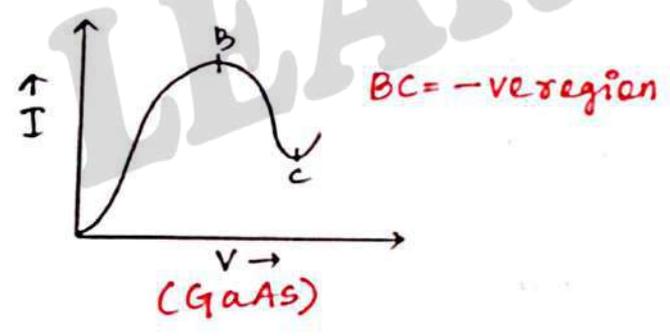
OHMIC SUBSTANCE:- Substance which obeys ohm's law.



eg:- all metals carrying low current.

NON-OHMIC SUBSTANCE:- Substance which doesn't obey ohm's law.

eg:- dil  $H_2SO_4$ , water voltameter, vacuum diode, GaAs



### TEMPERATURE DEPENDANCE OF RESISTIVITY:-

- $\rho_0$  → initial resistivity at temp  $T_0$
- $\rho$  → final resistivity at temp  $T$
- $\rho - \rho_0$  → change in resistivity.

$$\Rightarrow \rho - \rho_0 \propto (T - T_0)$$

$$\Rightarrow \rho - \rho_0 \propto \rho_0$$

$$\Rightarrow \rho - \rho_0 \propto \rho_0 (T - T_0)$$

$$\Rightarrow \rho - \rho_0 = \alpha \rho_0 (T - T_0) \quad , \quad \alpha = \text{temp. coefficient of resistivity.}$$

$$\Rightarrow \alpha = \frac{\rho - \rho_0}{\rho_0 (T - T_0)}$$

It is defined as the ratio between change in resistivity per original resistivity for degree rise of temp.

SI unit  $\rightarrow K^{-1}$

**CONDUCTOR:-** for conductor,  $\alpha = +ve$  i.e.  $\rho$  increases with  $\uparrow$  in temp.

Cause:- When temp  $\uparrow$ , K.E of free  $e^- \uparrow$  so no. of collision per sec  $\uparrow$ .  
Hence, resistivity  $\uparrow$ .

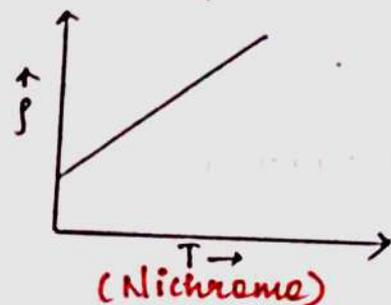
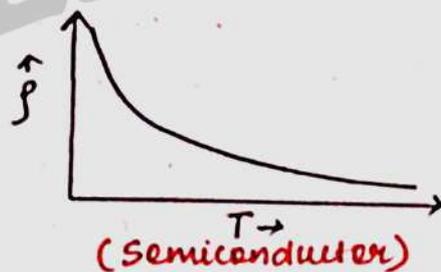
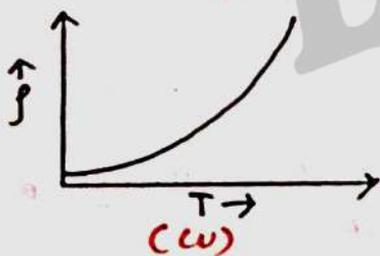
**SEMICONDUCTOR:-**  $\alpha = -ve$ , with  $\uparrow$  in temp,  $\rho \downarrow$

Cause:- When temp  $\uparrow$ , charge carrier density  $\uparrow$ ses which dominate the effect of  $Z$ .

$$\text{As } \rho = \frac{m}{ne^2Z} \quad , \quad \text{so } \rho \text{ decreases.}$$

**INSULATOR:-**  $\alpha = -ve$ ,  $\rho \downarrow$ ses with temperature.

**$\rho \sim T$  GRAPHS:-**



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USE OF ALLOY IN MAKING RESISTOR:-

- ①  $\rho$  of alloy is very high
- ② They have very small temp. of coefficient.
- ③ Least affected by atmospheric conditions such as air, moisture, pressure.

COLOUR CODE OF CARBON RESISTOR:-

- B  $\longrightarrow$  Black  $\longrightarrow$  0
  - B  $\longrightarrow$  Brown  $\longrightarrow$  1
  - R  $\longrightarrow$  Red  $\longrightarrow$  2
  - O  $\longrightarrow$  Orange  $\longrightarrow$  3
  - Y  $\longrightarrow$  Yellow  $\longrightarrow$  4
  - G  $\longrightarrow$  Green  $\longrightarrow$  5
  - B  $\longrightarrow$  Blue  $\longrightarrow$  6
  - V  $\longrightarrow$  Violet  $\longrightarrow$  7
  - G  $\longrightarrow$  Grey  $\longrightarrow$  8
  - W  $\longrightarrow$  White  $\longrightarrow$  9
  - G  $\longrightarrow$  Gold  $\longrightarrow$  5%
  - S  $\longrightarrow$  Silver  $\longrightarrow$  10%
  - N  $\longrightarrow$  No colour  $\longrightarrow$  20%
- } Tolerance

TRICK TO REMEMBER:- B B ROY of Great Britain had a Very Good Wife  
Wearing Gold & Silver Necklace.

INTERNAL RESISTANCE ( $r$ ):- The opposition offered by electrolyte due to flow of electric current is called internal resistance.

CAUSE:- Due to collision of ions.

- It depends on
- (1) nature of electrolyte and electrode
  - (2) area of electrode dipped in electrolyte.  
(more is the area, less is the internal resistance)
  - (3) distance between the two electrodes  
(more is the separation, more is the internal resistance)
  - (4) temperature  
(when temp ↑, internal resistance ↓ because viscosity decreases)

RELATION BETWEEN EMF AND POTENTIAL DIFFERENCE:-

(A) DISCHARGING CONDITION

$$E = V + Ir$$

(B) CHARGING CONDITION

$$V = E + Ir$$

COMBINATION OF CELL:-

(A) SERIES



for cell 1,  $V_{AC} = E_1 - Ir_1$   
 $\Rightarrow V_A - V_C = E_1 - Ir_1$  — (1)

for cell 2,  $V_{CB} = E_2 - Ir_2$   
 $\Rightarrow V_C - V_B = E_2 - Ir_2$  — (2)

Adding (1) & (2),

$$V_A - V_B = E_1 + E_2 - I(r_1 + r_2)$$
 — (3)

for the combination,

$$V_{AB} = E - Ir$$

$$\Rightarrow V_A - V_B = E - Ir$$
 — (4)

From eqn (3) & (4),

$$E_1 + E_2 - I(r_1 + r_2) = E - Ir$$

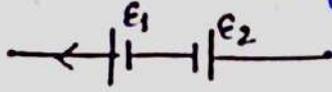
$$\Rightarrow E = E_1 + E_2$$

$$r = r_1 + r_2$$

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### SPECIAL CASE:-

If the connection is wrong

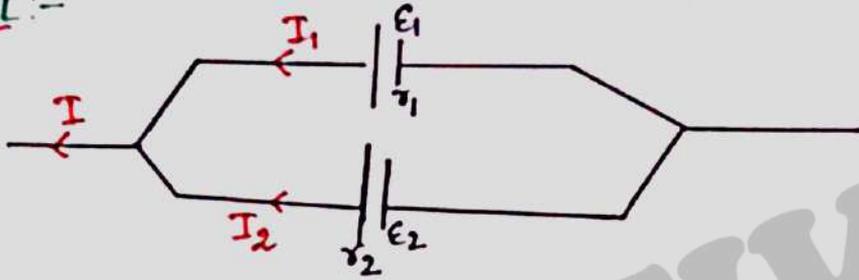


$$E = E_1 - E_2 \quad (\text{If } E_1 > E_2)$$

$$r = r_1 + r_2$$

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### (B) PARALLEL:-



for cell 1,  $V = E_1 - I_1 r_1 \Rightarrow I_1 = \frac{E_1 - V}{r_1}$  — (1)

for cell 2,  $I_2 = \frac{E_2 - V}{r_2}$  — (2)

Similarly for the combination,

$$I = \frac{E - V}{r} \quad \text{--- (3)}$$

$$I = I_1 + I_2$$

$$\Rightarrow \frac{E - V}{r} = \frac{E_1 - V}{r_1} + \frac{E_2 - V}{r_2}$$

$$\Rightarrow \frac{E}{r} - \frac{V}{r} = \frac{E_1 - V}{r_1} + \frac{E_2 - V}{r_2} \Rightarrow \frac{E}{r} - \frac{V}{r} = \left( \frac{E_1}{r_1} + \frac{E_2}{r_2} \right) - V \left( \frac{1}{r_1} + \frac{1}{r_2} \right)$$

Comparing both sides,

$$\frac{E}{r} = \frac{E_1}{r_1} + \frac{E_2}{r_2} \quad \& \quad \frac{1}{r} = \frac{1}{r_1} + \frac{1}{r_2} = \frac{r_1 + r_2}{r_1 r_2} \Rightarrow r = \frac{r_1 r_2}{r_1 + r_2}$$

$$= \frac{E_1 r_2 + E_2 r_1}{r_1 r_2} \cdot r = \frac{E_1 r_2 + E_2 r_1}{r_1 r_2} \cdot \frac{r_1 r_2}{r_1 + r_2}$$

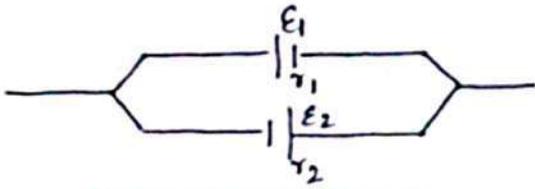
$$E = \frac{E_1 r_2 + E_2 r_1}{r_1 + r_2}$$

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SPECIAL CASE:-

CASE-I

If connection is wrong



$$E = \frac{E_1 r_2 - E_2 r_1}{r_1 + r_2}$$

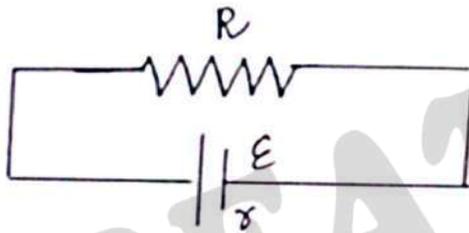
CASE-II :-

If  $E_1 = E_2 = E$

$r_1 = r_2 = r$

$$E_{net} = E$$

EXPRESSION OF CURRENT:-



$$E = V + I r$$

$$\Rightarrow E = IR + I r$$

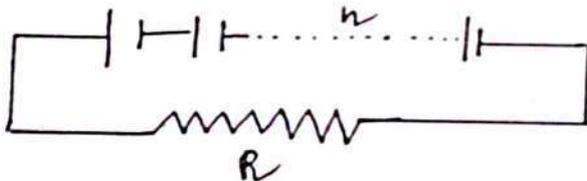
$$\Rightarrow E = I(R + r)$$

$$\Rightarrow I = \frac{E}{R + r}$$

$$I = \frac{\text{net emf}}{\text{net resistance}}$$

COMBINATION OF IDENTICAL CELL:-

(A) SERIES COMBINATION:-



$n = \text{no. of cells connected in series}$   
 net emf =  $nE$

$$I = \frac{nE}{nr + R} = \frac{nE}{nr + R} = \frac{nE}{nr + R}$$

### CASE-I

If  $R \gg nr$

$$I = \frac{nE}{R}$$

Current depends on no. of cells.

### CASE-II

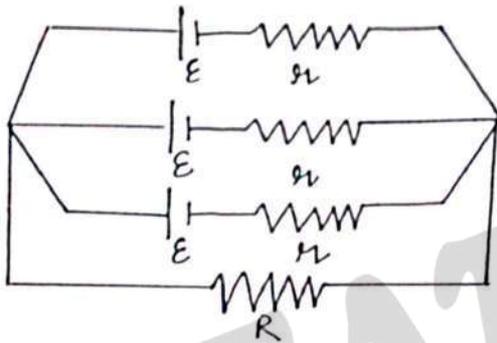
If  $R \ll nr$

$$I = \frac{E}{r}$$

Series connection is useful when external resistance is very large.

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### (B) PARALLEL COMBINATION :-



Total emf =  $E$

Net internal resistance =  $r/n$

Net resistance of entire network =  $R + \frac{r}{n}$

$$I = \frac{E}{R + \frac{r}{n}} = \frac{nE}{nR + r}$$

### CASE-I

If  $R \gg \frac{r}{n}$ ,  $r$  can be neglected

$$I = \frac{nE}{nR} = \frac{E}{R}$$

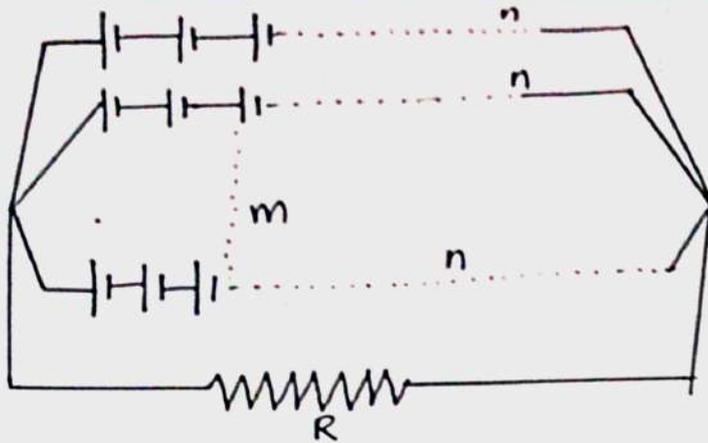
### CASE-II

If  $R \ll \frac{r}{n}$ ,  $R$  can be neglected

$$I = \frac{nE}{r} = n \left( \frac{E}{r} \right)$$

### MIXED CONNECTION :-

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$n = \text{no. of cells in each row}$   
 $m = \text{no. of such rows}$

Net emf =  $nE$

Net internal resistance =  $\frac{1}{R'} = \frac{1}{nr} + \frac{1}{nr} + \dots + \frac{1}{nr} \cdot m = \frac{m}{nr}$

$R' = \frac{nr}{m}$

$I = \frac{nE}{R + \frac{nr}{m}} = \frac{mnE}{Rm + nr}$

$mR + nr = (\sqrt{mR})^2 + (\sqrt{nr})^2 = (\sqrt{mR} - \sqrt{nr})^2 + 2\sqrt{mnr}$

Current will be max. when  $\sqrt{mR} = \sqrt{nr}$

$\Rightarrow mR = nr$

$\Rightarrow R = \frac{nr}{m}$

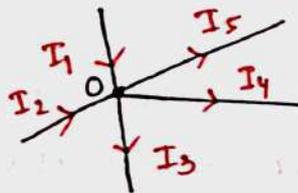
$\Rightarrow$  Total external resistance = Total internal resistance.

KIRCHHOFF'S LAWS:-

(a) KIRCHHOFF CURRENT LAW / JUNCTION LAW:-

It states that algebraic sum of currents meeting at a junction is zero.

$\Sigma I = 0$



The current coming towards the junction is taken as +ve.  
 The current going away from the junction is taken as -ve.

$$\rightarrow I_1 + I_2 - I_3 - I_4 - I_5 = 0$$

$$\rightarrow \boxed{I_1 + I_2 = I_3 + I_4 + I_5}$$

So, net current coming towards the junction = net current going out of the junction.

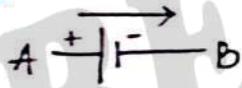
(b) KVL / loop law :-

It states that the algebraic sum of potential differences across cells and resistors in a close loop is 0.

$$\boxed{\sum \Delta V = 0}$$

SIGN CONVENTION:-

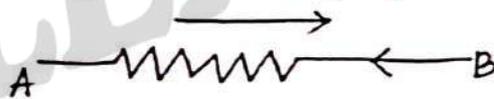
① If one moves from +ve to -ve of a cell, then emf is -ve



$$\Delta V = V_B - V_A$$

$$\boxed{E = -ve}$$

② If one moves opposite to direction of current then the product of current and resistance (IR) is taken as +ve.

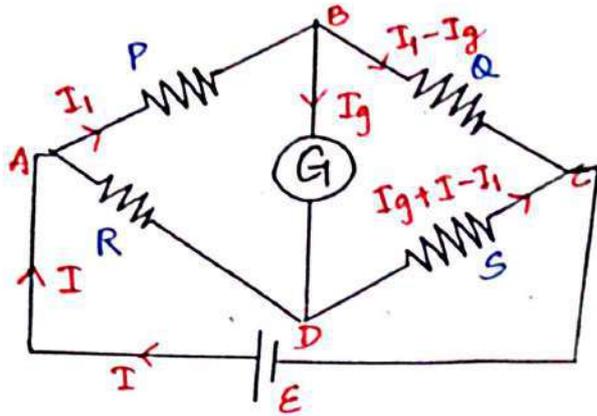


$$\Delta V = V_B - V_A$$

$$\Rightarrow \boxed{IR = +ve}$$

WHEATSTONE BRIDGE:-

P, Q, R, S are the 4 resistors connected in wheatstone bridge.  
 G → resistance of galvanometer.



Using KVL,

ABDA

$$-PI_1 - GI_g + R(I - I_1) = 0$$

$$-I_1P - I_gG + (I - I_1)R = 0 \quad \text{--- (I)}$$

BCDB

$$-Q(I_2 - I_g) + S(I - I_1 + I_g) + GI_g = 0 \quad \text{--- (II)}$$

The bridge is said to be balanced when no current passes through galvanometer  
i.e.  $I_g = 0$

eqn (I) & (II) becomes,

$$-I_1P + (I - I_1)R = 0$$

$$\boxed{(I - I_1)R = I_1P} \quad \text{--- (III)}$$

$$-QI_2 + SI - SI_1 = 0$$

$$\boxed{I_1Q = (I - I_1)S} \quad \text{--- (IV)}$$

Dividing (III) & (IV),

$$\boxed{\frac{P}{Q} = \frac{R}{S}}$$

It is the balanced condition of wheatstone bridge.

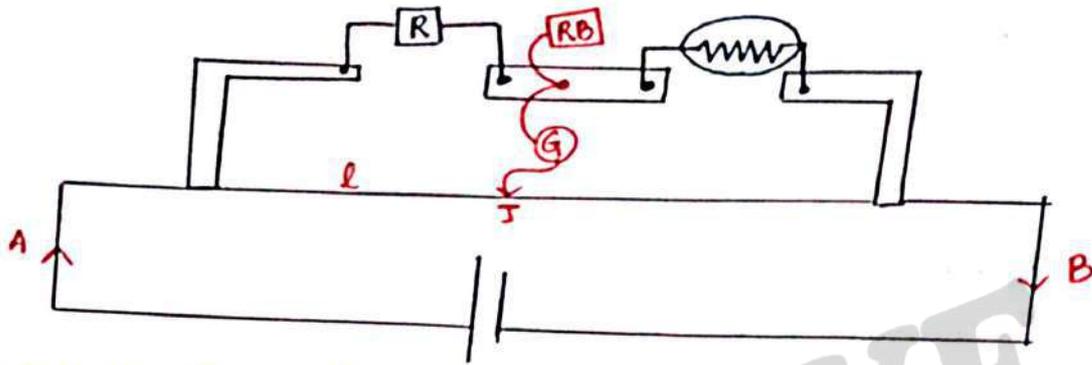
Q:- What happens to the balanced condition if cell & galvanometer are interchanged?

No change.

## METER BRIDGE :-

It is an electrical device used to measure unknown resistance.

PRINCIPLE :- It works on the balanced condition of wheatstone bridge.



$R$  = known resistance from resistance box

$S$  = unknown resistance

$J$  = null point such that  $AJ = l$

According to balanced condition of wheatstone bridge.

$$\frac{R}{S} = \frac{RAJ}{SBJ}$$

$$\Rightarrow \frac{R}{S} = \frac{l}{100-l}$$

$$\Rightarrow S = \frac{R(100-l)}{l}$$

Q :- When is metre bridge most sensitive?

If it is obtained at the middle of the wire

Q :- Why thick copper strips are used?

Because of negligible resistance

Q :- What happens to balancing length if resistance  $R$  increases?  
Increases.

## POTENTIOMETER

It is an electrical device which is used to measure emf of a cell.

PRINCIPLE OF POTENTIOMETER:-

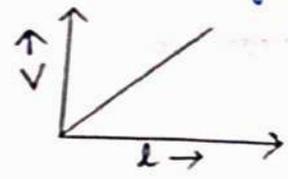
$$V = IR$$

$$\Rightarrow V = I \cdot l / A$$

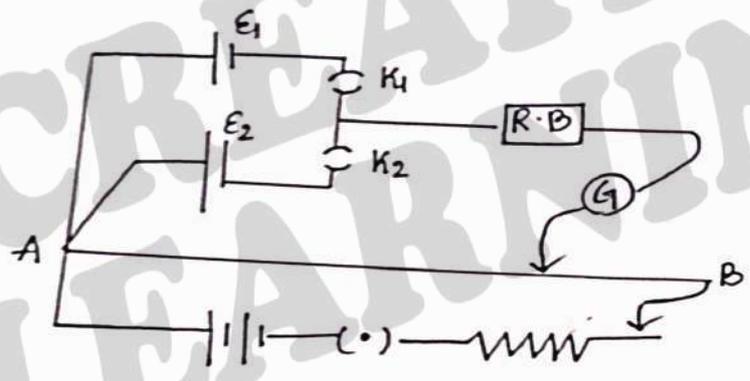
$$\Rightarrow V = \left( \frac{I \cdot l}{A} \right) l$$

$$\Rightarrow \boxed{V = Kl} , K = \frac{I \cdot l}{A}$$

The principle is that when a constant current flows through a wire of uniform cross-section and composition, the potential drop across any length of the wire is directly proportional to that length.



① Comparison of emf:-



- $E_1$  &  $E_2$  → are two primary cells
- $K_1$  &  $K_2$  → Two way key
- $R.B$  → Resistance box
- $E$  → Driving cell
- $K$  → Key of Auxillary / primary circuit
- $R$  → Rheostat
- $AB$  → potentiometer wire

Close  $K_1$ ,  $K_2$  is open

$$E_1 \propto l_1$$

$$\Rightarrow E_1 = Kl_1 \text{ --- (I)}$$

Close  $K_2$ ,  $K_1$  is open.

$$E_2 \propto l_2$$

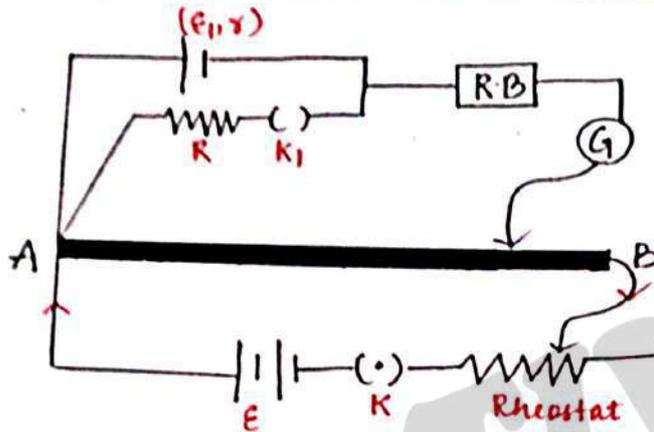
$$\Rightarrow E_2 = Kl_2 \text{ --- (II)}$$

Eqn ① by Eqn ②,

$$\frac{E_1}{E_2} = \frac{l_1}{l_2}$$

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② DETERMINATION OF INTERNAL RESISTANCE OF GIVEN PRIMARY CELL:-



CASE-I

$K_1$  is open

$E_1 \propto l_1 \Rightarrow E_1 = K l_1$  — ①

CASE-II

$V_1$  is closed

$V \propto l_2 \Rightarrow V = K l_2$  — ②

$$\frac{\text{Eqn ①}}{\text{Eqn ②}} = \frac{E_1}{V} = \frac{l_1}{l_2}$$

$$\Rightarrow \frac{I(R+r)}{IR} = \frac{l_1}{l_2}$$

$$\Rightarrow 1 + \frac{r}{R} = \frac{l_1}{l_2}$$

$$\Rightarrow \frac{r}{R} = \frac{l_1}{l_2} - 1$$

$$\Rightarrow r = \left( \frac{l_1 - l_2}{l_2} \right) R$$

$l_1$  = balancing length when only  $E_1$  is connected  
 $l_2$  = balancing length when  $R$  is connected

JM

### Chp-3: Current Electricity

- Flow of electrically charged particles (Charge-carriers) from electric current.

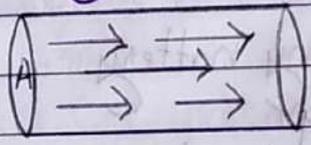
#### \* How current flows:

- Current flows through circuit.
- Strength of current ( $i$ ) - Electric strength passing through a cross-sectional area in unit time.

$$i = \frac{\text{charge}}{\text{time}} = \frac{Q}{t} = \frac{dQ}{dt}$$

- Unit of electric current is ampere (A).
- If in a circuit one coulomb charge flows in one second then intensity of current is one ampere.
- Electric current is a scalar quantity because it follows addition laws of scalar quantities and not a vector quantity.

#### \* Current density:



- Current per unit area is a vector quantity cause it depends on a direction

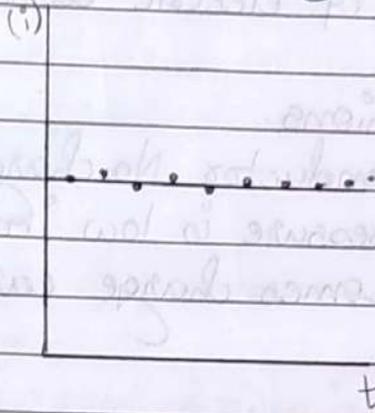
$$\vec{J} = \frac{i}{A} \quad J = \frac{i}{A}$$

$$i = j \cdot A \cos \theta$$

$$i = \vec{j} \cdot \vec{A}$$

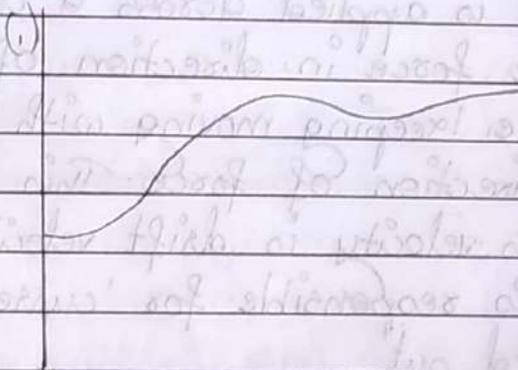
## \* Types of current:

### 1) Direct current (steady current):



Current value is constant as time passes and does not change its direction.

### 2) Variable current:



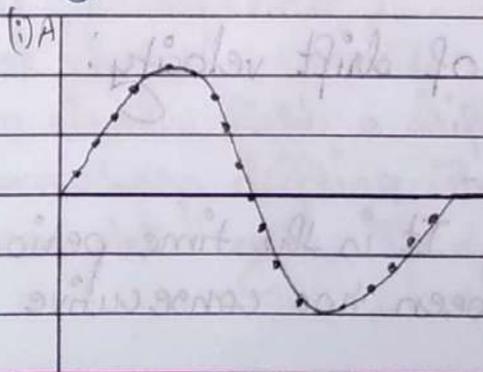
Magnitude is not same.

### 3) Instantaneous current:

- Current for an instant

(i) Charging current & (ii) Discharging current.

### 4) Alternating current (AC):



Don't have same value at every instant and can change direction.

### \* Charge carriers:

- Charge carriers are the particle which carry charge and move during flow of electric current.
- Metals: Electrons
- Electrolytes: Cations & anions.
- Gases: Gases are bad conductors. No charge carriers.
- Special condition: When pressure is low in gas electrons leave the atom and becomes charge carrier.

### \* Drift velocity:

- When electric field is applied across a conductor free electrons experience force in direction of higher potential and while keeping moving with thermal velocity drift in direction of force. This phenomena is drifting and its velocity is drift velocity.
- This drift velocity is responsible for 'current' because this is not cancelled out.
- This drift velocity is very small to the order of  $10^{-1}$  mm/s but still it is effective to make current because the number of electron carrying in same direction is very very less.  $i = ne$

### \* ~~Deriving~~

### \* Deriving expression of drift velocity:

- Relaxation time ' $\tau$ ' -

It is the time period for electron elapsed between two consecutive collision

$$\tau = \tau_1 + \tau_2 + \tau_3 + \dots + \tau_n \quad (\text{Temperature decrease } \tau \text{ decreases})$$

$$V = u + at$$

$$\text{If } u = 0$$

$$V = at$$

$$a = \frac{F}{m} = \frac{-e \cdot E}{m}$$

$$V_i = \frac{-e \cdot E \cdot \tau_i}{m} \quad \& \quad V_{av} = \frac{-e \cdot E \cdot \tau}{m}$$

- This average velocity is due to application of  $E$  in one direction. Hence this is drift velocity.

$$V_d = \frac{-e \cdot E \cdot \tau}{m}$$

$V_d$  depends upon  $E$  &  $\tau$ .

If temperature increases  $\tau$  decreases therefore  $V_d$  decreases.

### \* Electric current and drift velocity:

(A) A conductor has length  $l$  area of cross-section 'A'.

'n' is electron density per unit volume.

$$\therefore \text{Total electron} = nAl$$

$$\therefore \text{Total charge } q = -enAl$$

- Due to electric field a drift velocity  $V_d$  is set up and electrons keep drifting. Time period for all electrons to drift complete length  $T = \frac{l}{V_d}$ .

- Now current  $(i) = \frac{q}{t}$  or  $i = \frac{-enAv_d}{t}$   
 $= -neAv_d$

-ve sign shows that direction of electric current is taken as opposite direction of  $v_d$  of electron.  
 Magnitude for the charge  $i = neAv_d$

\* Mobility:

- Mobility of a charge carrier in a particular medium is drift velocity developed when electric field applied is unity.

Mobility  $\mu = \frac{v_d}{E}$   $\frac{ms^{-1}}{Vm^{-1}} = m^2 s^{-1} V^{-1}$  } Unit

- Dimensions:  $LATT^{-1} M^{-1} A^{-1} T^{+2} = AM^{-1} T^2$

- Drift velocity  $(u) = \frac{-qE}{m} = \frac{-q\tau}{m}$

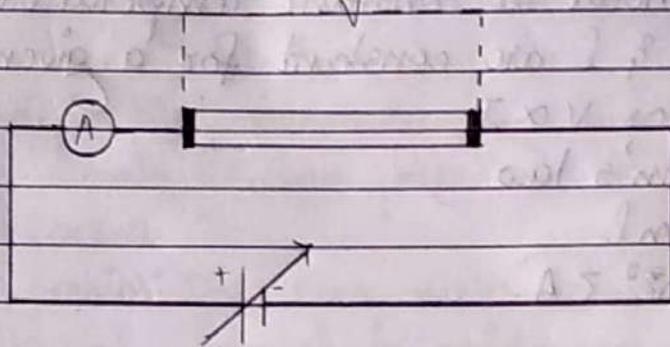
- Mobility of electron  $\mu_e = \frac{-e\tau}{m}$

- Mobility of hole  $\mu_h = \frac{e\tau}{m_h}$

- Eg,

Material	Mobility $e^-$	Mobility hole <sup>+</sup>
1. Diamond	1800 $cm^2 v^{-1} s^{-1}$	1200
2. Silicon	1350 $cm^2 v^{-1} s^{-1}$	480
3. Gallium Arsenic	8000 $cm^2 v^{-1} s^{-1}$	300

\* Ohm's law:



- Potential difference applied across a conductor is directly proportional to current flowing in it. Provided all the physical condition (temperature & pressure) remains same.

$$V \propto I \quad V = RI$$

$$\therefore R = \frac{V}{I} \text{ (Ratio of voltage to current)}$$

R = resistance.

\* Proof of Ohm's law:

$$I = n \cdot e \cdot A \cdot v_d$$

$$I = \frac{-neAeE\tau}{m}$$

$$= \frac{-ne^2AE\tau}{m}$$

$$E = \frac{dv}{dx} \text{ Here } E = \frac{V}{l}$$

$$\text{To } dx$$

$$I = \frac{-ne^2A\tau V}{ml}$$

Here,  $e$  and  $m$  are constant of electron  $n$  is constant for given metal at constant temperature,  $Z$  is constant.  $A$  &  $l$  are constant for a given sample.

$$\therefore I \propto V \text{ or } V \propto I$$

This is Ohm's law

$$\therefore \frac{V}{I} = R = \frac{ml}{ne^2 ZA}$$

### \* Resistivity or specific resistance:

(1)  $R \propto l$     (2)  $R \propto \frac{1}{A}$

After combining

$$R \propto \frac{l}{A}$$

$$R = \rho \frac{l}{A} \quad \therefore \rho = R \times \frac{A}{l}$$

$\rho$  - Resistivity or specific resistance

If  $A=1$  and  $l=1$ .

$$\therefore \rho = R$$

We know that  $R = \frac{ml}{ne^2 ZA}$

but  $l$  and  $A=1$  and then  $R = \rho$

$$\therefore \rho = \frac{m}{ne^2 Z} \quad \text{And } \rho \text{ is dependent on metal.}$$

- Resistivity is equal to resistance of a block of conductor across two opposite faces which have area of cross-section in unity and distance between them as one unit.

- Unit of resistance = ohm  $\Omega$   
 1 Ohm resistance :-

If  $V=1$  and  $I=1$  then  $R=1\Omega$

One Ohm is that resistance in which current of one ampere develops when potential difference of 1V is applied across it.

- Unit of resistivity = Ohm-meter =  $\Omega m$

- Resistivity of a metal is resistance between two opposite faces of a unit cube of that metal.

Q What is resistance?

Ans Resistance is opposition faced by charges while moving in a conductor. Basic cause of resistance is collision.

\* Conductance & Conductivity:

$$G = \frac{1}{R}$$

$$\text{Conductance} = \frac{1}{\text{Resistance}}$$

- Property of conductor is conductance and conductivity.

$$\sigma = \frac{1}{\rho}$$

where,

$\sigma$  - conductivity

$\rho$  - resistivity

$$\sigma = \frac{1}{\Omega m} = \Omega^{-1} m^{-1}$$

\* Microscopic form of Ohm's law:

$$I = \frac{V}{R}$$

$$jA = \frac{\rho l}{A}$$

where,  $j$  is current density and  $\rho$  is resistivity.

$$j = \frac{E}{\rho}$$

$$\vec{j} = \sigma \cdot \vec{E}$$

" $\sigma$ " is current conductivity of a material".

Q When wire is drawn to double length, then what is the change in resistance?

$$\rho = \frac{RA}{l}$$

$$R = \frac{\rho l}{A}$$

Here  $\rho$  constant,  $l$  and  $A$  changes volume does not change.

$$V = A_1 l_1 \quad \therefore A_1 l_1 = A_2 l_2$$

$$V = A_2 l_2$$

$$\frac{A_1}{A_2} = \frac{l_2}{l_1} \quad \text{--- (i) } l_2 = 2l_1 \quad \text{--- (ii)}$$

$$R_1 = \frac{\rho l_1}{A_1}$$

$$\text{So, } R_2 = \frac{l_2 A_1}{A_2^2} = \frac{A_1^2}{A_2^2} = \left[ \frac{2}{1} \right]^2 = 4$$

$$\therefore R_2 = 4R_1$$

### \* General formula:

-  $l$  increases  $n$  times

$A$  decreases  $n$  times

$$R_1 = \frac{\rho l}{A} \quad \text{--- (i) } R_2 = \frac{\rho l n}{A/n}$$

$$\therefore R_2 = \frac{\rho l n^2}{A}$$

From eq (i)

$$R_2 = n^2 R_1 \quad \text{--- General formula}$$

### \* Effect of temperature on resistivity:

#### 1) Metal (conductors):

Temperature increases, resistivity increases.

Reason -

Temperature increases  $\rightarrow$  Thermal velocity increases  
 $\rightarrow$  Relaxation period decreases  $\rightarrow$  Number of collision per second increases  $\rightarrow$  Resistance increases.

Thermal co-efficient of resistivity -

This is increase in resistance ( $\alpha$ ) of a sample material whose resistance is in ohm and its temperature increases by  $1^\circ\text{C}$ .

Eq:  $R_0 \rightarrow \text{heat} \rightarrow \Delta T \rightarrow R$

Increase per unit resistance =  $\frac{R - R_0}{R_0 \Delta T} = \alpha$

$\alpha = \frac{R - R_0}{R_0 \Delta T}$  Unit of  $\alpha = K^{-1}$

Dimension:  $T^{-1}$

$$R = R_0 + \alpha R_0 \Delta T$$

$$R = R_0 (1 + \alpha \Delta T)$$

2) Alloy:

Show very small (negligible) value of  $\alpha$   
Resistance do not change with temperature in alloys.  
Due to this property alloys are used as standard resistance in lab.

3) Electrolyte:

(Liquid) temperature increases  $\rightarrow$  resistance decreases  
Reason -

At higher temperature the density decrease (becomes thin) so for ions it is easier to move, that is resistance decreases.

4) Semiconductor:

Temperature increases  $\rightarrow$  Resistance decreases.

$$\text{Resistivity } (\rho) = \frac{m}{ne^2 \tau}$$

Reason -

Due to temperature increase number of free electron (population) increases very rapidly, therefore resistance decreases.

The effect of decrease of  $\tau$  is not that strong hence negligible.

5) Insulators  
 Temperature increases  $\rightarrow$  Resistance decreases.  
 Reason-

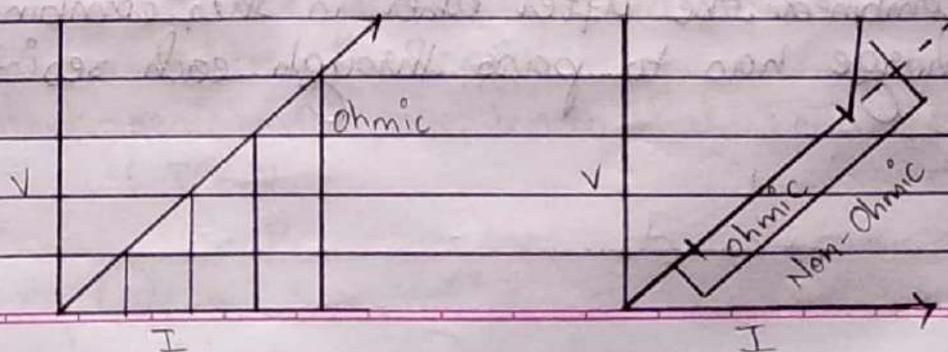
At very high temperature electrons are ejected out of atoms becomes free electrons. Conductivity increases and resistance decreases. Finally it is breakdown of insulators.

6) Thermistors  
 Their resistance changes very rapidly with temperature for this property they are used in thermometer.

7) Superconductors  
 These are the materials whose resistance is zero. Super conductors are made at very low temperature. The lower temperature of which a material becomes super conductor is called critical temperature.

Material	Critical temp	Applications
Lead	4.2 K	Make strong electromagnet
Mercury	7.25 K	Research high energy particle
$\text{Bi}_2\text{Ca}_2\text{Sr}_2\text{Cu}_3\text{O}_{10}$	105 K	High speed computer
$\text{Tl}_2\text{Ba}_2\text{Cu}_3\text{O}_{10}$	125 K	Transmission of electric power.

\* Non-Ohmic resistor or non-Ohmic behaviour:



The circuits and components which do not follow Ohm's law  $V \propto I$  are called Non-Ohmic circuit. This non-Ohmic ~~circuit~~ linear behaviour is non-Ohmic behaviour. Eg: Meter at high current, semiconductor, etc.

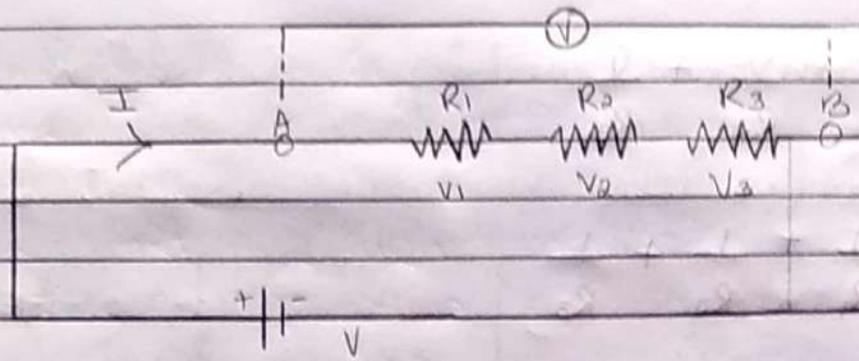
\* Carbon-resistors:

Colour	Number	Multiplier	Tolerance
Black	0	$10^0 = 1$	
Brown	1	$10^1$	
Red	2	$10^2$	
Orange	3	$10^3$	
Yellow	4	$10^4$	
Green	5	$10^5$	
Blue	6	$10^6$	
Violet	7	$10^7$	
Grey	8	$10^8$	
White	9	$10^9$	
Gold		$10^{-1}$	5%
Silver		$10^{-2}$	10%
			No colour = 20%

\* Combination of resistors:

1) Series combination:

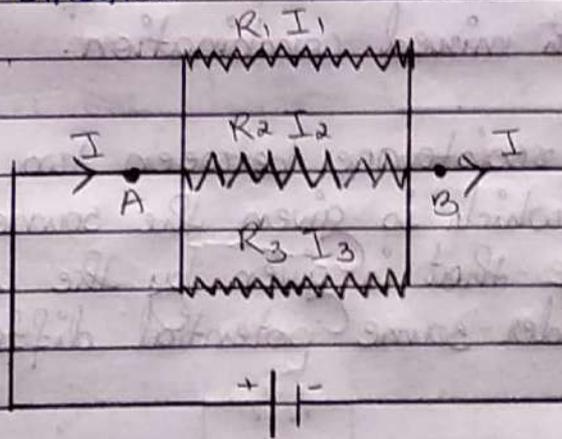
Combined one after other in this combination, charge has to pass through each resistor.



- $V = V_1 + V_2 + V_3$  (Potential difference is divided)
- Current  $I$  is same through all resistors in series.
- Equivalent resistance between A & B is,  

$$R_{AB} = \frac{V_{AB}}{I_{AB}} = \frac{V_1 + V_2 + V_3}{I_{AB}} = R_1 + R_2 + R_3$$
- In series resistance increases:  
 $n$  Resistance in series  $\rightarrow nR$ .
- Current in circuit  $I = \frac{V}{R_1 + R_2 + R_3}$

## 2) Parallel combination:



- Current is divided:  $I = I_1 + I_2 + I_3$
- Potential difference across the resistor is same as that across battery (source)  $V$ .
- Equivalent resistance, we know that  $I = I_1 + I_2 + I_3$  (1)  

$$R_e = \frac{V}{I} \quad \therefore I = \frac{V}{R}$$

So in eq (1)

$$V = V + V + V$$

$$R_e \quad R_1 \quad R_2 \quad R_3$$

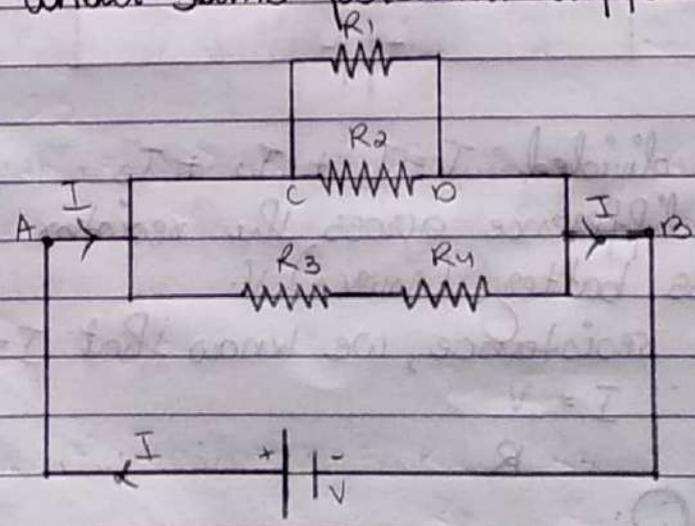
$$= \frac{1}{R_e} = \frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3}$$

$$\therefore R_e = \left[ \frac{1}{R_1} + \frac{1}{R_2} + \frac{1}{R_3} \right]^{-1}$$

- In parallel combination resistance decreases. The equivalent resistance is less than the smallest resistance.
- For 2 resistance,  $R_1$  &  $R_2$  :  $R_e = \frac{R_1 \cdot R_2}{R_1 + R_2}$
- For 'n' similar resistor in parallel  $R_e = \frac{R}{n}$

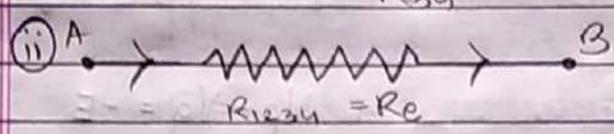
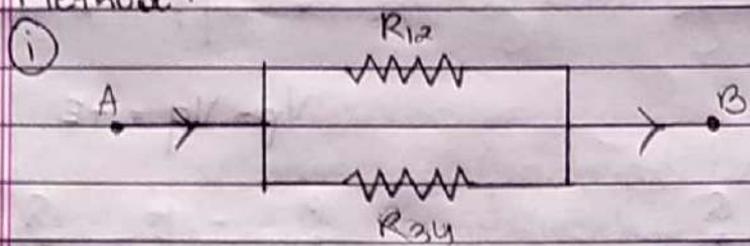
**\* Circuit with mixed combination:**

Equivalent resistance between two point is that resistance which is given the same value of current and voltage that is given by the combination of resistor, under same potential difference.



$T = \frac{V}{R_e}$  (Only for 2 point or 1 resistor)

Method:



\* Kirchoff's rules:

⇒ Junction rule or current rule:

Junction is a point in a circuit which has more than 2 lines meet.

Branch is a current path from one junction to next. Current from one junction to next current throughout is same.

Loop-

A closed path of current.

Junction rule:

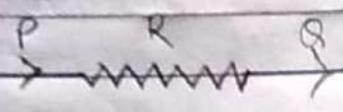
(1) The sum of all current at the junction is zero.  
 $\sum i = 0$

(2) Current approaching in a junction is equal to current leaving out.

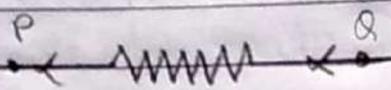
⇒ Loop rule or voltage rule:

In a closed loop the sum of potential across element is zero  $\sum V = 0$ .

Calculation

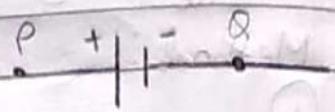


$V_p - V_q = +ve.$



$V_p - V_q = -ve$

Calculation =

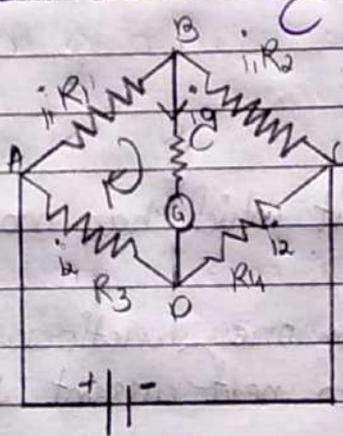


$V_p - V_q = +E$



$V_p - V_q = -E$

\* Wheat-stone bridge:



Unbalanced: When there is current in galvanometer  $V_B \neq V_A$ .

Balanced: When there is no current in galvanometer  $V_B = V_A$ .

Applying Kirchoff's law:

Loop ABAA  $\Rightarrow$

$i_1 R_1 - i_2 R_3 = 0 \Rightarrow i_1 R_1 = i_2 R_3$  or  $\frac{i_1}{i_2} = \frac{R_3}{R_1}$  — (i)

Loop BODB,

$i_1 R_2 - i_2 R_4 = 0 \Rightarrow i_1 R_2 = i_2 R_4$  or  $\frac{i_1}{i_2} = \frac{R_4}{R_2}$  — (ii)

By eq (i) & (ii)

$\frac{R_3}{R_1} = \frac{R_4}{R_2} \Rightarrow \text{sc interchange} \Rightarrow \frac{R_1}{R_2} = \frac{R_3}{R_4}$

It is possible only when  $i_g = 0$  as bridge is balanced.

\* Cell:

- Internal resistance -

Resistance created by electrolyte to the moving ions inside cell 'x'.

- Factors on which internal resistance depends:

- ① Distance between electrode increases 'x'.
- ② Larger dipping of electrode decreases 'x' cause area increases.
- ③ Temperature increases 'x' decreases cause electrolyte becomes thin.

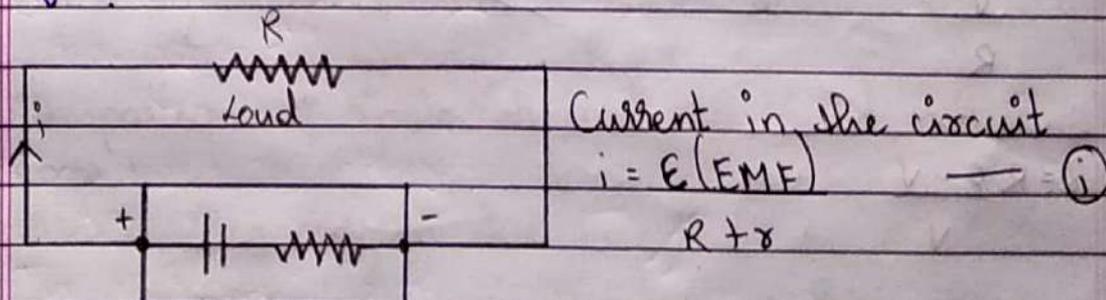
\* EMF:

- EMF of a cell is amount of work done in rotating one unit charge through complete cycle. Symbol - (E)

- Terminal potential difference -

Work done by a unit charge while moving from one terminal of battery to other in outer circuit. Symbol 'v' unit volt.

\* Relation between EMF 'E' & terminal potential difference 'v':



Terminal potential difference,  $V = iR$  — (ii)

Condition 1:

Battery discharging work getting done from eq (i)

$$E = iR + ir$$

$$E = V + ir$$

$V = E - ir$  (Terminal potential difference  $V$  is always smaller than EMF ' $E$ ')

Condition 2:

Circuit open. No use of battery then  $i = 0$ .

$$V = E$$

Condition 3:

When a battery is getting recharged, then during that time terminal potential difference is more than EMF ' $E$ '.

\* Relation between terminal potential difference and internal resistance:

$$V = E - ir$$

$$ir = E - V$$

$$r = \frac{E - V}{i}$$

$$r = \frac{E - V}{\frac{V}{R}}$$

$$r = R \frac{E - V}{V}$$

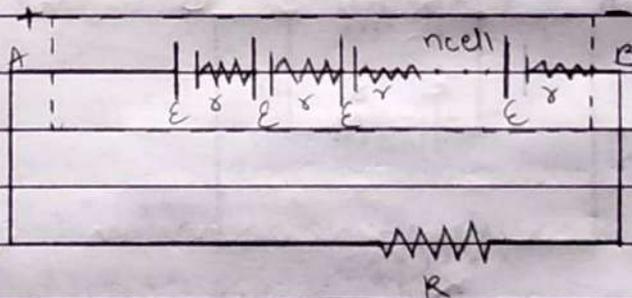
$$r = R \left( \frac{E}{V} - 1 \right)$$

Here  $r$  is the internal resistance.

- In our household supply when load increases the current increases according to relation  $V = E - ir$ . When the current increases, the terminal potential difference 'v' decreases. Therefore the potential difference in the main line decreases. Therefore all bulbs and other equipments experience lower voltage.

### \* Combinations of cells:

#### 1) Series combination:



Net EMF =  $nE$

Total resistance =  $nr + R$

Current =  $\frac{nE}{nr + R}$

For a single cell current =  $\frac{E}{R + r}$

Comparison of single cell and combined cell:

Case 1:

$R \gg r$ , then current due to cell is  $\frac{E}{R}$ .

Current in series =  $\frac{nE}{R}$

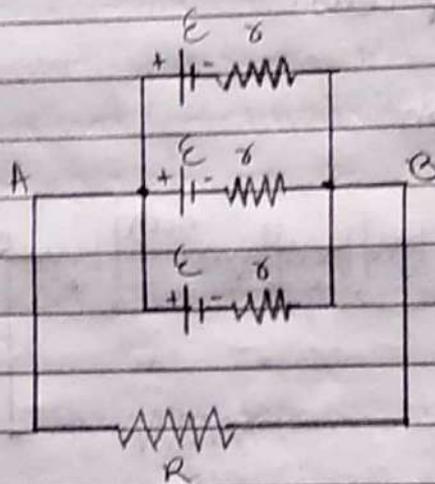
∴ Current increases

Case 2:

$R \ll r$ . Current due to single cell =  $\frac{E}{r}$

Current in series is =  $\frac{nE}{nr} = \frac{E}{r}$

2) Parallel combination:



EMF Net =  $E$

Resistance =  $\frac{r}{n} + R$

=  $\frac{nR + r}{n}$

Current =  $\frac{E}{\frac{nR + r}{n}} = \frac{nE}{nR + r}$

∴  $i_p = \frac{nE}{nR + r}$

Comparing single cell and combination in parallel

For single cell =  $\frac{E}{R+x}$

Case 1:

$R \gg x$

$i_p = \frac{nE}{nR+x}$  (neglecting  $x$ )

$= \frac{E}{R}$

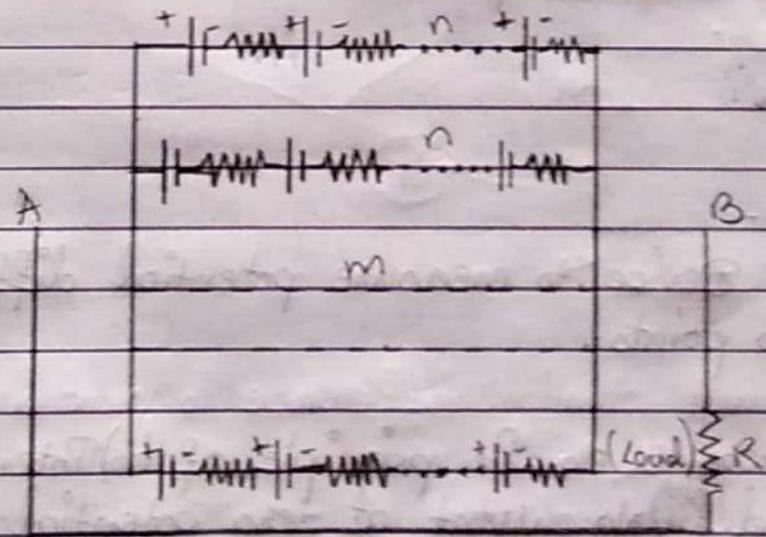
For single cell  $i = \frac{E}{R}$

Case 2:

$i_p = \frac{nE}{x}$  (neglecting  $R$ )

For single cell  $i = \frac{E}{x}$

3) Mixed combination:



EMF across one row:  $nE$  (series)

EMF across parallel rows remain unchanged.

EMF across AB =  $nE$ .

In one row series resistance =  $nx$ .

$$A \text{ to } B \quad R_{AB} = \frac{n\alpha}{m} + R$$

$$\text{Current in circuit } i = \frac{n\epsilon}{\frac{n\alpha}{m} + R} = \frac{m \times n\epsilon}{n\alpha + mR}$$

$$\text{Condition for maximum current}$$

$$i = \frac{m \times n\epsilon}{n\alpha + mR}$$

- Current will be maximum when  $n\alpha + mR$  is smallest  
condition for  $n\alpha + mR$  to be small:

W.K.T

$$(n\alpha + mR)^2 = (n\alpha - mR)^2 + 4m\alpha nR$$

Condition for  $n\alpha + mR$  to be minimum is  $n\alpha - mR = 0$ .

$$n\alpha = mR$$

$$\frac{n}{m} = \frac{R}{\alpha}$$

This is the condition for maximum current.

### \* Potentiometer:

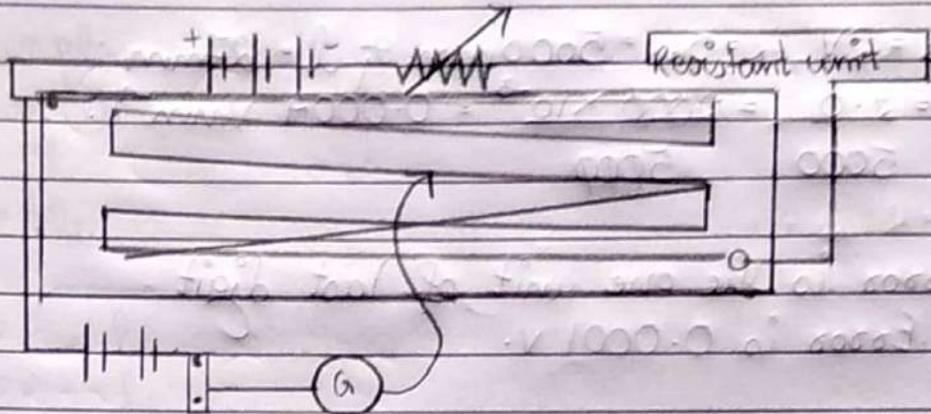
#### - Introduction -

Device to measure potential difference between two points.

#### - Principle -

It works on the principle of (i) Potential gradient and (ii) No current at zero potential.

#### - Description:



If  $V$  is potential difference given by source battery then potential drop per mm is  $\frac{V}{L}$  where  $L$  is the total

length of resistance wire.

Potential difference across  $l$  mm  $V \times \frac{l}{L}$ .

$V = Pl$  where,  $P$  - potential gradient.

- In a potentiometer, the potential gradient is fallen of potential per unit length of wire.

Q Why potentiometer is a better device than voltmeter?

Ans When voltmeter is fitted in a circuit it draws some current from its own operation, therefore current in main circuit decreases and potential difference gets lesser reading. Whereas in potentiometer the reading is taken when circuit is zero. Hence there is no potential loss. Therefore potentiometer gives accurate and precise operation.

Q A battery having 2V potential difference is applied across potentiometer wire of 5 meter. To find -

- ① What is the potential gradient of this instrument?
- ② Across a length of 27mm, how much is the potential difference and what is possible error in it?

Ans  $V_s = 2V$ ,  $L = 5m = 5000mm$  &  $l = 27mm$   

$$p = \frac{2.0}{5000} = \frac{2000 \times 10^{-3}}{5000} = 0.0004 \text{ Vmm}^{-1}$$

Error is the one unit of last digit  
 $\therefore$  Error is  $0.0001V$ .

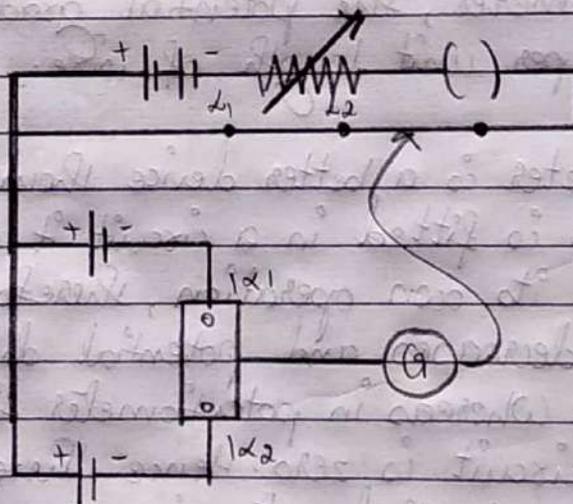
$V = pl$

$V = 0.0004 \times 27 = 0.0108 \text{ Vmm}^{-1}$

- Application of potentiometer:

① Comparison of EMF of 2 cells:

Voltmeter cannot measure EMF because there is never no-current situation, but EMF can be measured by potentiometer.



Working-

A small potential difference is created across potentiometer. By trial point  $D_1$  is searched such that deflection in galvanometer is zero. Then potential difference  $V = pl$  is balanced by  $PE$  by cell 1.

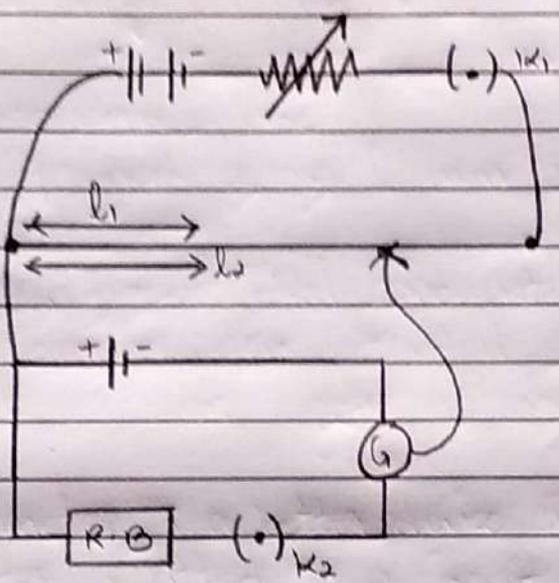
$\therefore E_1 = pl_1$  (Because at zero current  $V = E$ ).

$K_1$  is open  $K_2$  is closed. Repeated experiment and null point located at  $D_2$  with cell

$\therefore E_2 = \rho l_2$  — (ii)  
 By eq (i) & (ii)  
 $E_1 = \rho l_1$   
 $E_2 = \rho l_2$

$\therefore E_1 = l_1$   
 $E_2 = l_2$

② To find out internal resistance of a cell:



Procedure:

①  $k_1$  is close,  $k_2$  is open

Null point found at  $l_1$

$E = \rho l_1$  — (i) (Current zero  $\therefore V_1 = E$ )

② A resistance  $R$  is taken out and  $k_2$  is closed. Again null point is searched found at distance  $l_2$ .

$V = \rho l_2$  — (ii)

$E = \rho l_1$

$V = \rho l_2$

$E = l_1$

$V = l_2$

$$\delta = R \left( \frac{E - 1}{V} \right)$$

$$\delta = R \left( \frac{l_1 - 1}{l_2} \right)$$

① -  $\sqrt{g} = 1.3$   
② -  $\sqrt{g} = 1.3$   
③ -  $\sqrt{g} = 1.3$   
④ -  $\sqrt{g} = 1.3$   
⑤ -  $\sqrt{g} = 1.3$